NSN 5961-01-597-1327

Mil-std (military Standard):

spec.

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-597-1327 **Inclosure Material:** Glass **Overall Length:** Between 0.200 inches and 0.225 inches **Overall Height:** Between 0.137 inches and 0.148 inches **Overall Width:** Between 0.137 inches and 0.148 inches **End Application:** E-3 block 404 **Mounting Method:** Press fit **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 reverse voltage, peak **Current Rating Per Characteristic:** 125.00 amperes peak forward surge current **Product Name:** Mil spec: semiconductor device, diode, silicon, ultrafast recovery, power rectifier, type jantx1n5809us **Terminal Type And Quantity:** 2 bonding pad Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0